#### **Features**

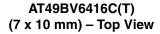
- 64-megabit (4M x 16) Flash Memory
- 2.7V 3.6V Read/Write
- High Performance
  - Asynchronous Access Time 70 ns
  - Page Mode Read Time 20 ns
- Sector Erase Architecture
  - Eight 4K Word Sectors with Individual Write Lockout
  - One Hundred Twenty-seven 32K Word Main Sectors with Individual Write Lockout
- Typical Sector Erase Time: 32K Word Sectors 700 ms; 4K Word Sectors 200 ms
- Four Plane Organization, Permitting Concurrent Read in Any of the Three Planes not Being Programmed/Erased
  - Memory Plane A: 16M Memory Including Eight 4K Word Sectors
  - Memory Plane B: 16M Memory Consisting of 32K Word Sectors
  - Memory Plane C: 16M Memory Consisting of 32K Word Sectors
  - Memory Plane D: 16M Memory Consisting of 32K Word Sectors
- Suspend/Resume Feature for Erase and Program
  - Supports Reading and Programming Data from Any Sector by Suspending Erase of a Different Sector
  - Supports Reading Any Word by Suspending Programming of Any Other Word
- Low-power Operation
  - 30 mA Active
  - 35 µA Standby
- 2.2V I/O Option Reduces Overall System Power
- VPP Pin for Write Protection and Accelerated Program/Erase Operations
- RESET Input for Device Initialization
- CBGA Package
- Top or Bottom Boot Block Configuration Available
- 128-bit Protection Register
- Common Flash Interface (CFI)

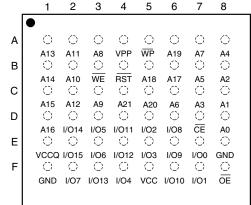
# **Description**

The AT49BV6416C(T) is a 2.7-volt 64-megabit Flash memory. The memory is divided into multiple sectors and planes for erase operations. The device can be read or reprogrammed off a single 2.7V power supply, making it ideally suited for In-System programming. The device can operate in the asynchronous or page read mode.

# **Pin Configurations**

Pin Name	Pin Function
I/O0 - I/O15	Data Inputs/Outputs
A0 - A21	Addresses
CE	Chip Enable
ŌĒ	Output Enable
WE	Write Enable
RESET	Reset
WP	Write Protect
VPP	Write Protection and Power Supply for Accelerated Program/Erase Operations
VCCQ	Output Power Supply







64-megabit (4M x 16) Page Mode 2.7-volt Flash Memory

AT49BV6416C AT49BV6416CT

3465B-FLASH-11/04





The AT49BV6416C(T) is divided into four memory planes. A read operation can occur in any of the three planes which is not being programmed or erased. This concurrent operation allows improved system performance by not requiring the system to wait for a program or erase operation to complete before a read is performed. To further increase the flexibility of the device, it contains an Erase Suspend and Program Suspend feature. This feature will put the erase or program on hold for any amount of time and let the user read data from or program data to any of the remaining sectors. There is no reason to suspend the erase or program operation if the data to be read is in another memory plane.

The VPP pin provides data protection and faster programming and erase times. When the  $V_{PP}$  input is below 0.7V, the program and erase functions are inhibited. When  $V_{PP}$  is at 1.65V or above, normal program and erase operations can be performed. With  $V_{PP}$  at 12.0V, the program (Dual-word Program command) and erase operations are accelerated.

# Device Operation

**COMMAND SEQUENCES:** When the device is first powered on, it will be in the read mode. Command sequences are used to place the device in other operating modes such as program and erase. The command sequences are written by applying a low pulse on the  $\overline{WE}$  input with  $\overline{CE}$  low and  $\overline{OE}$  high or by applying a low-going pulse on the  $\overline{CE}$  input with  $\overline{WE}$  low and  $\overline{OE}$  high. The address is latched on the first rising edge of the  $\overline{WE}$  or  $\overline{CE}$ . Valid data is latched on the rising edge of the  $\overline{WE}$  or the  $\overline{CE}$  pulse, whichever occurs first. The addresses used in the command sequences are not affected by entering the command sequences.

ASYNCHRONOUS READ: The AT49BV6416C(T) is accessed like an EPROM. When  $\overline{\text{CE}}$  and  $\overline{\text{OE}}$  are low and  $\overline{\text{WE}}$  is high, the data stored at the memory location determined by the address pins are asserted on the outputs. The outputs are put in the high impedance state whenever  $\overline{\text{CE}}$  or  $\overline{\text{OE}}$  is high. This dual-line control gives designers flexibility in preventing bus contention.

**PAGE READ:** The page read operation of the device is controlled by  $\overline{\text{CE}}$  and  $\overline{\text{OE}}$  inputs. The page size is four words. The first word access of the page read is the same as the asynchronous read. The first word is read at an asynchronous speed of 70 ns. Once the first word is read, toggling A0 and A1 will result in subsequent reads within the page being output at a speed of 20 ns. The page read diagram is shown on page 22.

**RESET:** A RESET input pin is provided to ease some system applications. When RESET is at a logic high level, the device is in its standard operating mode. A low level on the RESET pin halts the present device operation and puts the outputs of the device in a high-impedance state. When a high level is reasserted on the RESET pin, the device returns to read mode.

**ERASE:** Before a word can be reprogrammed it must be erased. The erased state of the memory bits is a logical "1". The entire memory can be erased by using the Chip Erase command or individual planes can be erased by using the Plane Erase command or individual sectors can be erased by using the Sector Erase command.

**CHIP ERASE**: Chip Erase is a two-bus cycle operation. The automatic erase begins on the rising edge of the last  $\overline{\text{WE}}$  pulse. Chip Erase does not alter the data of the protected sectors. The hardware reset during chip erase will stop the erase, but the data will be of an unknown state.

**PLANE ERASE:** As an alternative to a full Chip Erase, the device is organized into four planes that can be individually erased. The Plane Erase command is a two-bus cycle operation. The plane whose address is valid at the second rising edge of  $\overline{\text{WE}}$  will be erased. The Plane Erase command does not alter the data in the protected sectors.

**SECTOR ERASE:** The device is organized into multiple sectors that can be individually erased. The Sector Erase command is a two-bus cycle operation. The sector whose address is valid at the second rising edge of  $\overline{\text{WE}}$  will be erased provided the given sector has not been protected.

**WORD PROGRAMMING:** The device is programmed on a word-by-word basis. Programming is accomplished via the internal device command register and is a two-bus cycle operation. The programming address and data are latched in the second cycle. The device will automatically generate the required internal programming pulses. Please note that a "0" cannot be programmed back to a "1"; only erase operations can convert "0"s to "1"s.

**FLEXIBLE SECTOR PROTECTION:** The AT49BV6416C(T) offers two sector protection modes, the Softlock and the Hardlock. The Softlock mode is optimized as sector protection for sectors whose content changes frequently. The Hardlock protection mode is recommended for sectors whose content changes infrequently. Once either of these two modes is enabled, the contents of the selected sector is read-only and cannot be erased or programmed. Each sector can be independently programmed for either the Softlock or Hardlock sector protection mode. At power-up and reset, all sectors have their Softlock protection mode enabled.

**SOFTLOCK AND UNLOCK:** The Softlock protection mode can be disabled by issuing a two-bus cycle Unlock command to the selected sector. Once a sector is unlocked, its contents can be erased or programmed. To enable the Softlock protection mode, a two-bus cycle Softlock command must be issued to the selected sector.

**HARDLOCK AND WRITE PROTECT** ( $\overline{WP}$ ): The Hardlock sector protection mode operates in conjunction with the Write Protection ( $\overline{WP}$ ) pin. The Hardlock sector protection mode can be enabled by issuing a two-bus cycle Hardlock software command to the selected sector. The state of the Write Protect pin affects whether the Hardlock protection mode can be overridden.

- When the WP pin is low and the Hardlock protection mode is enabled, the sector cannot be unlocked and the contents of the sector is read-only.
- When the WP pin is high, the Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.

To disable the Hardlock sector protection mode, the chip must be either reset or power cycled.

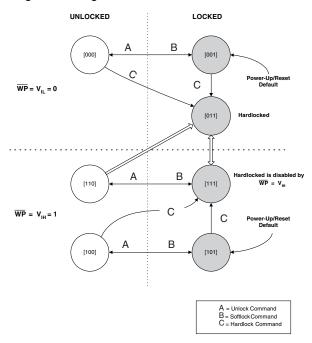
**Table 1.** Hardlock and Softlock Protection Configurations in Conjunction with  $\overline{WP}$ 

V <sub>PP</sub>	WP	Hard- lock	Soft- lock	Erase/ Prog Allowed?	Comments
V <sub>CC</sub>	0	0	0	Yes	No sector is locked
V <sub>cc</sub>	0	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
V <sub>CC</sub>	0	1	1	No	Hardlock protection mode is enabled. The sector cannot be unlocked.
V <sub>CC</sub>	1	0	0	Yes	No sector is locked.
V <sub>CC</sub>	1	0	1	No	Sector is Softlocked. The Unlock command can unlock the sector.
V <sub>CC</sub>	1	1	0	Yes	Hardlock protection mode is overridden and the sector is not locked.
V <sub>cc</sub>	1	1	1	No	Hardlock protection mode is overridden and the sector can be unlocked via the Unlock command.
V <sub>IL</sub>	х	Х	Х	No	Erase and Program Operations cannot be performed.





Figure 1. Sector Locking State Diagram



Note: 1. The notation [X, Y, Z] denotes the locking state of a sector. The current locking state of a sector is defined by the state of  $\overline{WP}$  and the two bits of the sector-lock status D[1:0].

**SECTOR PROTECTION DETECTION:** A software method is available to determine if the sector protection Softlock or Hardlock features are enabled. When the device is in the software product identification mode a read from the I/O0 and I/O1 at address location 00002H within a sector will show if the sector is unlocked, softlocked, or hardlocked.

Table 2. Sector Protection Status

I/O1	1/00	Sector Protection Status
0	0	Sector Not Locked
0	1	Softlock Enabled
1	0	Hardlock Enabled
1	1	Both Hardlock and Softlock Enabled

**READ STATUS REGISTER**: The status register indicates the status of device operations and the success/failure of that operation. The Read Status Register command causes subsequent reads to output data from the status register until another command is issued. To return to reading from the memory, issue a Read command.

The status register bits are output on I/O7 - I/O0. The upper byte, I/O15 - I/O8, outputs 00H when a Read Status Register command is issued.

The contents of the status register [SR7:SR0] are latched on the falling edge of  $\overline{OE}$  or  $\overline{CE}$  (whichever occurs last), which prevents possible bus errors that might occur if status register contents change while being read.  $\overline{CE}$  or  $\overline{OE}$  must be toggled with each subsequent status read, or the status register will not indicate completion of a Program or Erase operation.

When the Write State Machine (WSM) is active, SR7 will indicate the status of the WSM; the remaining bits in the status register indicate whether the WSM was successful in performing the preferred operation (see Table 3).

Table 3. Status Register Bit Definition

WSMS	ESS	ES	PRS	VPPS	PSS	SLS	PLS
7	6	5	4	3	2	1	0
					No	tes	
SR7 WRITE ST 1 = Ready 0 = Busy	TATE MACHINE S	STATUS (WSMS)				rst to determine \ ore checking prog	
1 = Erase Susp	SUSPEND STAT ended ogress/Complete			both WSMS and		WSM halts exect - ESS bit remains ssued.	
SR5 = ERASE STATUS (ES)  1 = Error in Sector Erase  0 = Successful Sector Erase						has applied the n still unable to ve	
SR4 = PROGRAM STATUS (PRS)  1 = Error in Programming  0 = Successful Programming				When this bit is program a word		has attempted bu	ut failed to
SR3 = VPP STATUS (VPPS)  1 = VPP Low Detect, Operation Abort  0 = VPP OK			level. The WSN Erase command system if V <sub>PP</sub> has	l interrogates V <sub>PF</sub> d sequences hav	de continuous ind level only after the been entered a hed on. The V <sub>PP</sub> y the WSM.	he Program or nd informs the	
SR2 = PROGRAM SUSPEND STATUS (PSS)  1 = Program Suspended  0 = Program in Progress/Completed			When Program Suspend is issued, WSM halts execution and sets both WSMS and PSS bits to "1". PSS bit remains set to "until a Program Resume command is issued.				
1 = Prog/Erase	SR1 = SECTOR LOCK STATUS 1 = Prog/Erase attempted on a locked sector; Operation aborted. 0 = No operation to locked sectors			sectors, this bit	is set by the WS	is attempted to or M. The operation ed to read status	specified is
SR0 = Plane St	. ,			Indicates progra		s of the addresse	ed plane.

Note: 1. A Command Sequence Error is indicated when SR1, SR3, SR4 and SR5 are set.

 Table 4. Status Register Device WSMS and Write Status Definition

WSMS (SR7)	PLS (SR0)	Description
0	0	The addressed plane is performing a program/erase operation.
0	1	A plane other than the one currently addressed is performing a program/erase operation.
1	х	No program/erase operation is in progress in any plane. Erase and Program suspend bits (SR6, SR2) indicate whether other planes are suspended.





**ERASE SUSPEND/ERASE RESUME:** The Erase Suspend command allows the system to interrupt a sector erase or plane erase operation. The erase suspend command does not work with the Chip Erase feature. Using the erase suspend command to suspend a sector erase operation, the system can program or read data from a different sector within the same plane. Since this device is organized into four planes, there is no need to use the erase suspend feature while erasing a sector when you want to read data from a sector in another plane. After the Erase Suspend command is given, the device requires a maximum time of 15 µs to suspend the erase operation. After the erase operation has been suspended, the plane that contains the suspended sector enters the erase-suspend-read mode. The system can then read data or program data to any other sector within the device. An address is not required during the Erase Suspend command. During a sector erase suspend, another sector cannot be erased. To resume the sector erase operation, the system must write the Erase Resume command. The Erase Resume command is a one-bus cycle command, which does require the plane address. Read, Read Status Register, Product ID Entry, Clear Status Register, Program, Program Suspend, Erase Resume, Sector Softlock/Hardlock, Sector Unlock are valid commands during an erase suspend.

PROGRAM SUSPEND/PROGRAM RESUME: The Program Suspend command allows the system to interrupt a programming operation and then read data from a different word within the memory. After the Program Suspend command is given, the device requires a maximum of 10 µs to suspend the programming operation. After the programming operation has been suspended, the system can then read from any other word within the device. An address is not required during the program suspend operation. To resume the programming operation, the system must write the Program Resume command. The program suspend and resume are one-bus cycle commands. The command sequence for the erase suspend and program suspend are the same, and the command sequence for the erase resume and program resume are the same. Read, Read Status Register, Product ID Entry, Program Resume are valid commands during a Program Suspend.

128-BIT PROTECTION REGISTER: The AT49BV6416C(T) contains a 128-bit register that can be used for security purposes in system design. The protection register is divided into two 64-bit blocks. The two blocks are designated as block A and block B. The data in block A is non-changeable and is programmed at the factory with a unique number. The data in block B is programmed by the user and can be locked out such that data in the block cannot be reprogrammed. To program block B in the protection register, the two-bus cycle Program Protection Register command must be used as shown in the Command Definition table on page 13. To lock out block B, the two-bus cycle lock protection register command must be used as shown in the Command Definition table. Data bit D1 must be zero during the second bus cycle. All other data bits during the second bus cycle are don't cares. To determine whether block B is locked out, the Status of Sector B Protection command is given. If data bit D1 is zero, block B is locked. If data bit D1 is one, block B can be reprogrammed. Please see the Protection Register Addressing Table on page 14 for the address locations in the protection register. To read the protection register, the Product ID Entry command is given followed by a normal read operation from an address within the protection register. After determining whether block B is protected or not or reading the protection register, the Read command must be given to return to the read mode.

**CFI:** Common Flash Interface (CFI) is a published, standardized data structure that may be read from a flash device. CFI allows system software to query the installed device to determine the configurations, various electrical and timing parameters, and functions supported by the device. CFI is used to allow the system to learn how to interface to the flash device most optimally. The two primary benefits of using CFI are ease of upgrading and second source availability. The command to enter the CFI Query mode is a one-bus cycle command which requires writing data 98h to any address. The CFI Query command can be written when the device is ready to read data or can also be written when the part is in the product ID mode. Once in the CFI Query mode, the system can read CFI data at the addresses given in Table 5 on page 25. To return to the read mode, the read command should be issued.

**HARDWARE DATA PROTECTION:** Hardware features protect against inadvertent programs to the AT49BV6416C(T) in the following ways: (a)  $V_{CC}$  sense: if  $V_{CC}$  is below 1.8V (typical), the device is reset and the program and erase functions are inhibited. (b)  $V_{CC}$  power-on delay: once  $V_{CC}$  has reached the  $V_{CC}$  sense level, the device will automatically time-out 10 ms (typical) before programming. (c) Program inhibit: holding any one of  $\overline{OE}$  low,  $\overline{CE}$  high or  $\overline{WE}$  high inhibits program cycles. (d) Noise filter: pulses of less than 15 ns (typical) on the  $\overline{WE}$  or  $\overline{CE}$  inputs will not initiate a program cycle. (e)  $V_{PP}$  is less than  $V_{ILPP}$ .

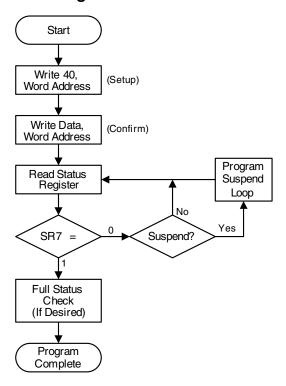
**INPUT LEVELS:** While operating with a 2.7V to 3.6V power supply, the address inputs and control inputs ( $\overline{OE}$ ,  $\overline{CE}$  and  $\overline{WE}$ ) may be driven from 0 to 2.5V without adversely affecting the operation of the device. The I/O lines can be driven from 0 to  $V_{CCQ} + 0.6V$ .

**OUTPUT LEVELS:** For the AT49BV6416C(T), output high levels are equal to  $V_{CCQ}$  - 0.1V (not  $V_{CC}$ ). For 2.7V to 3.6V output levels,  $V_{CCQ}$  must be tied to  $V_{CC}$ .





## **Word Program Flowchart**



#### **Word Program Procedure**

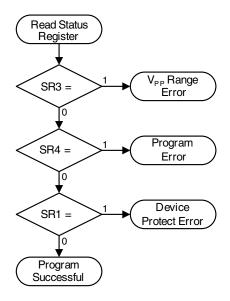
Bus Operation	Command	Comments
Write	Program Setup	Data = 40 Addr = Location to program
Write	Data	Data = Data to program Addr = Location to program
Read	None	Status register data: Toggle CE or OE to update status register
ldle	None	Check SR7 1 = WSM Ready 0 = WSM Busy

Repeat for subsequent Word Program operations.

Full status register check can be done after each program, or after a sequence of program operations.

Write FF after the last operation to set to the Read state.

#### **Full Status Check Flowchart**



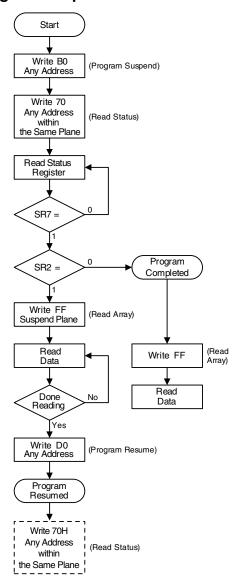
#### **Full Status Check Procedure**

Bus Operation	Command	Comments			
Idle	None	Check SR3: 1 = V <sub>PP</sub> Error			
Idle	None	Check SR4: 1 = Data Program Error			
Idle	None	Check SR1: 1 = Sector locked; operation aborted			

SR3 MUST be cleared before the Write State Machine allows further program attempts.

If an error is detected, clear the status register before continuing operations – only the Clear Status Register command clears the status register error bits.

# **Program Suspend/Resume Flowchart**



## **Program Suspend/Resume Procedure**

Bus Operation	Command	Comments
Write	Program Suspend	Data = B0 Addr = Sector address to Suspend (SA)
Write	Read Status	Data = 70 Addr = Any address within the Same Plane
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register Addr = Any address
Idle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
Idle	None	Check SR2 1 = Program suspended 0 = Program completed
Write	Read Array	Data = FF Addr = Any address within the Suspended Plane
Read	None	Read data from any sector in the memory other than the one being programmed
Write	Program Resume	Data = D0 Addr = Any address

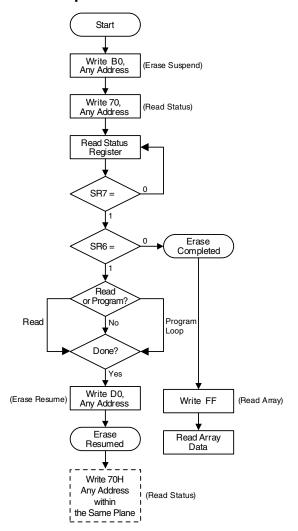
## If the Suspend Plane was placed in Read mode:

Write	Read	Return Plane to Status mode:
	Status	Data = 70
		Addr = Any address within the Same Plane





# **Erase Suspend/Resume Flowchart**



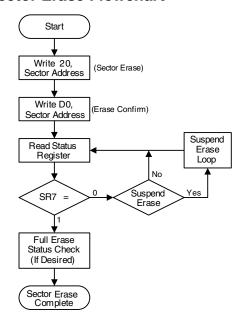
## **Erase Suspend/Resume Procedure**

Bus	_	
Operation	Command	Comments
Write	Erase Suspend	Data = B0 Addr = Any address within the Same Plane
Write	Read Status	Data = 70 Addr = Any address
Read	None	Status register data: Toggle $\overline{CE}$ or $\overline{OE}$ to update status register Addr = Any address within the Same Plane
ldle	None	Check SR7 1 = WSM Ready 0 = WSM Busy
ldle	None	Check SR6 1 = Erase suspended 0 = Erase completed
Write	Read or Program	Data = FF or 40 Addr = Any address
Read or Write	None	Read or program data from/to sector other than the one being erased
Write	Program Resume	Data = D0 Addr = Any address

#### If the Suspended Plane was placed in Read mode or a Program loop:

Write	Read	Return Plane to Status mode:
	Status	Data = 70
		Addr = Any address within the Same Plane

#### **Sector Erase Flowchart**



#### **Sector Erase Procedure**

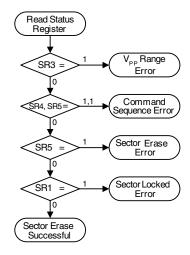
Bus Operation	Command	Comments
Write	Sector Erase Setup	Data = 20 Addr = Sector to be erased (SA)
Write	Erase Confirm	Data = D0 Addr = Sector to be erased (SA)
Read	None	Status register data: Toggle CE or OE to update status register data
Idle	None	Check SR7 1 = WSMS Ready 0 = WSMS Busy

Repeat for subsequent sector erasures.

Full status register check can be done after each sector erase, or after a sequence of sector erasures.

Write FF after the last operation to enter read mode.

#### **Full Erase Status Check Flowchart**



## **Full Erase Status Check Procedure**

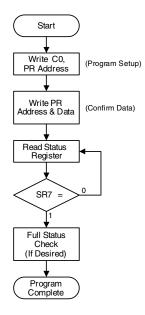
Bus Operation	Command	Comments
Idle	None	Check SR3: 1 = V <sub>PP</sub> Range Error
Idle	None	Check SR4, SR5: Both 1 = Command Sequence Error
Idle	None	Check SR5: 1 = Sector Erase Error
Idle	None	Check SR1: 1 = Attempted erase of locked sector; erase aborted.

SR1, SR3 must be cleared before the Write State Machine allows further erase attempts.

Only the Clear Status Register command clears SR1, SR3, SR4, SR5. If an error is detected, clear the status register before attempting an erase retry or other error recovery.



# Protection Register Programming Flowchart



## **Protection Register Programming Procedure**

Bus Operation	Command	Comments
Write	Program PR Setup	Data = C0 Addr = First Location to Program
Write	Protection Program	Data = Data to Program  Addr = Location to Program
Read	None	Status register data: Toggle CE or OE to update status register data
Idle	None	Check SR7 1 = WSMS Ready 0 = WSMS Busy

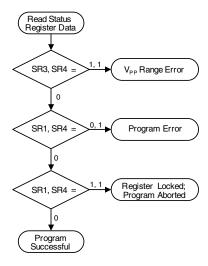
Program Protection Register operation addresses must be within the protection register address space. Addresses outside this space will return an error.

Repeat for subsequent programming operations.

Full status register check can be done after each program, or after a sequence of program operations.

Write FF after the last operation to return to the Read mode.

#### **Full Status Check Flowchart**



#### **Full Status Check Procedure**

Bus Operation	Command	Comments
Idle	None	Check SR1, SR3, SR4: 0,1,1 = V <sub>PP</sub> Range Error
Idle	None	Check SR1, SR3, SR4: 0,0,1 = Programming Error
Idle	None	Check SR1, SR3, SR4: 1, 0,1 = Sector locked; operation aborted

SR3 must be cleared before the Write State Machine allows further program attempts.

Only the Clear Status Register command clears SR1, SR3, SR4. If an error is detected, clear the status register before attempting a program retry or other error recovery.

# **Command Definition Hex**<sup>(1)</sup>

	Bus	1st Bu Cycl		2nd Bo Cycle		3rd E Cyc	
Command Sequence	Cycles	Addr	Data	Addr	Data	Addr	Data
Read	1	PA <sup>(2)</sup>	FF				
Chip Erase	2	XX	21	Addr	D0		
Plane Erase	2	xx	22	Addr	D0		
Sector Erase	2	SA <sup>(3)</sup>	20	SA <sup>(3)</sup>	D0		
Word Program	2	Addr <sup>(4)</sup>	40/10	Addr <sup>(4)</sup>	D <sub>IN</sub>		
Dual Word Program <sup>(5)</sup>	3	Addr0	E0	Addr0	D <sub>IN0</sub>	Addr1	D <sub>IN1</sub>
Erase/Program Suspend	1	xx	B0				
Erase/Program Resume	1	PA <sup>(2)</sup>	D0				
Product ID Entry <sup>(6)(7)</sup>	1	PA <sup>(2)</sup>	90				
Sector Softlock	2	SA <sup>(3)</sup>	60	SA <sup>(3)</sup>	01		
Sector Hardlock	2	SA <sup>(3)</sup>	60	SA <sup>(3)</sup>	2F		
Sector Unlock	2	SA <sup>(3)</sup>	60	SA <sup>(3)</sup>	D0		
Read Status Register	2	PA <sup>(2)</sup>	70	PA <sup>(7)</sup>	D <sub>OUT</sub> <sup>(8)</sup>		
Clear Status Register	1	xx	50				
Program Protection Register– Block B	2	xxxx <sup>(10)</sup> 8x <sup>(9)</sup>	C0	xxxx <sup>(10)</sup> 8x <sup>(9)</sup>	D <sub>IN</sub>		
Lock Protection Register – Sector B	2	xxxx80 <sup>(10)</sup>	C0	xxxx80 <sup>(10)</sup>	FFFD		
Status of Sector B Protection	2	xxxx80 <sup>(10)</sup>	90	xxxx80 <sup>(10)</sup>	D <sub>OUT</sub> <sup>(11)</sup>		
CFI Query	1	XX	98				

Notes:

- 1. The DATA FORMAT shown for each bus cycle is as follows; I/O7 I/O0 (Hex). I/O15 I/O8 are don't care. The ADDRESS FORMAT shown for each bus cycle is as follows: A7 A0 (Hex). Address A21 through A8 are don't care.
- 2. PA is the plane address (A21 A20). Any address within a plane can be used.
- 3. SA = sector address. Any word address within a sector can be used to designate the sector address (see pages 15 18 for details).
- 4. The first bus cycle address should be the same as the word address to be programmed.
- 5. This fast programming option enables the user to program two words in parallel only when V<sub>PP</sub> = 12V. The addresses, Addr0 and Addr1, of the two words, D<sub>IN0</sub> and D<sub>IN1</sub>, must only differ in address A0. This command should be used during manufacturing purposes only.
- 6. During the second bus cycle, the manufacturer code is read from address PA+00000H, the device code is read from address PA+00001H, and the data in the protection register is read from addresses 000081H 000088H.
- 7. The plane address should be the same during the first and second bus cycle.
- 8. The status register bits are output on I/O7 I/O0.
- 9. Any address within the user programmable protection register region. Please see "Protection Register Addressing Table" on page 14
- 10. For the AT49BV6416C, xxxx = 0000H. For the AT49BV6416CT, xxxx = 3F80H.
- 11. If data bit D1 is "0", sector B is locked. If data bit D1 is "1", sector B can be reprogrammed.





# **Absolute Maximum Ratings\***

Temperature under Bias55°C to +125°C	;
Storage Temperature65°C to +150°C	)
All Input Voltages Except V <sub>PP</sub> (Including NC Pins) with Respect to Ground0.6V to +2.5V	/
V <sub>PP</sub> Input Voltage with Respect to Ground0V to 12.5V	/
All Output Voltages with Respect to Ground0.6V to $V_{\text{CCQ}}$ + 0.6V	/

\*NOTICE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **Protection Register Addressing Table**

Word	Use	Block	A7	A6	<b>A</b> 5	<b>A</b> 4	А3	A2	<b>A</b> 1	A0
0	Factory	Α	1	0	0	0	0	0	0	1
1	Factory	Α	1	0	0	0	0	0	1	0
2	Factory	Α	1	0	0	0	0	0	1	1
3	Factory	Α	1	0	0	0	0	1	0	0
4	User	В	1	0	0	0	0	1	0	1
5	User	В	1	0	0	0	0	1	1	0
6	User	В	1	0	0	0	0	1	1	1
7	User	В	1	0	0	0	1	0	0	0

Notes: 1. For the AT49BV6416C, all address lines not specified in the above table, A21 - A8, must be 0 when accessing the Protection Register.

<sup>2.</sup> For the AT49BV6416CT, all address lines not specified in the table, A21 - A8, must be 3F80H when accessing the Protection Register.

## **Memory Organization - AT49BV6416C**

			x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
Α	SA0	4K	00000 - 00FFF
Α	SA1	4K	01000 - 01FFF
Α	SA2	4K	02000 - 02FFF
Α	SA3	4K	03000 - 03FFF
Α	SA4	4K	04000 - 04FFF
Α	SA5	4K	05000 - 05FFF
Α	SA6	4K	06000 - 06FFF
Α	SA7	4K	07000 - 07FFF
Α	SA8	32K	08000 - 0FFFF
Α	SA9	32K	10000 - 17FFF
Α	SA10	32K	18000 - 1FFFF
Α	SA11	32K	20000 - 27FFF
Α	SA12	32K	28000 - 2FFFF
A	SA13	32K	30000 - 37FFF
A	SA14	32K	38000 - 3FFFF
A	SA15	32K	40000 - 47FFF
A	SA16	32K	48000 - 4FFFF
A	SA17	32K	50000 - 57FFF
A	SA18	32K	58000 - 5FFFF
Α	SA19	32K	60000 - 67FFF
A	SA20	32K	68000 - 6FFFF
		32K	70000 - 77FFF
A	SA21		
A	SA22	32K	78000 - 7FFFF
A	SA23	32K	80000 - 87FFF
A	SA24	32K	88000 - 8FFFF
Α	SA25	32K	90000 - 97FFF
Α	SA26	32K	98000 - 9FFFF
Α	SA27	32K	A0000 - A7FFF
Α	SA28	32K	A8000 - AFFFF
Α	SA29	32K	B0000 - B7FFF
Α	SA30	32K	B8000 - BFFFF
Α	SA31	32K	C0000 - C7FFF
Α	SA32	32K	C8000 - CFFFF
Α	SA33	32K	D0000 - D7FFF
Α	SA34	32K	D8000 - DFFFF
Α	SA35	32K	E0000 - E7FFF
Α	SA36	32K	E8000 - EFFFF
Α	SA37	32K	F0000 - F7FFF
Α	SA38	32K	F8000 - FFFFF
В	SA39	32K	100000 - 107FFF
В	SA40	32K	108000 - 10FFFF
В	SA41	32K	110000 - 117FFF
В	SA42	32K	118000 - 11FFFF
В	SA43	32K	120000 - 127FFF
В	SA44	32K	128000 - 12FFFF

# Memory Organization - AT49BV6416C (Continued)

Plane         Sector         Size (Words)         Address Range (A21 - A0)           B         SA45         32K         130000 - 137FFF           B         SA46         32K         138000 - 13FFFF           B         SA47         32K         140000 - 147FFF           B         SA48         32K         148000 - 14FFFF           B         SA49         32K         150000 - 157FFF           B         SA50         32K         158000 - 15FFFF           B         SA51         32K         160000 - 167FFF           B         SA51         32K         168000 - 16FFFF           B         SA52         32K         168000 - 17FFFF           B         SA53         32K         170000 - 17FFFF           B         SA53         32K         180000 - 18FFFF           B         SA53         32K         180000 - 18FFFF           B         SA56         32K         190000 - 19FFFF           B         SA57         32K         190000 - 19FFFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1BFFFF           B         SA62         32K <td< th=""><th></th></td<>	
B         SA46         32K         138000 - 13FFFF           B         SA47         32K         140000 - 147FFF           B         SA48         32K         148000 - 14FFFF           B         SA49         32K         150000 - 157FFF           B         SA50         32K         158000 - 15FFFF           B         SA51         32K         160000 - 167FFF           B         SA52         32K         168000 - 16FFFF           B         SA53         32K         170000 - 17FFFF           B         SA53         32K         178000 - 17FFFF           B         SA54         32K         180000 - 187FFF           B         SA55         32K         180000 - 18FFFF           B         SA56         32K         190000 - 197FFF           B         SA53         32K         190000 - 19FFFF           B         SA58         32K         198000 - 19FFFF           B         SA53         32K         190000 - 17FFF           B         SA60         32K         180000 - 18FFFF           B         SA61         32K         180000 - 18FFFF           B         SA62         32K         180000 - 10FFFF	)
B         SA47         32K         140000 - 147FFF           B         SA48         32K         148000 - 14FFFF           B         SA49         32K         150000 - 157FFF           B         SA50         32K         158000 - 15FFFF           B         SA51         32K         160000 - 167FFF           B         SA51         32K         168000 - 16FFFF           B         SA52         32K         178000 - 177FFF           B         SA53         32K         178000 - 17FFFF           B         SA54         32K         180000 - 18FFFF           B         SA55         32K         180000 - 18FFFF           B         SA56         32K         198000 - 19FFFF           B         SA53         32K         198000 - 19FFFF           B         SA56         32K         198000 - 18FFFF           B         SA57         32K         190000 - 18FFFF           B         SA60         32K         180000 - 18FFFF           B         SA61         32K         180000 - 18FFFF           B         SA63         32K         180000 - 107FFF           B         SA64         32K         100000 - 107FFF	
B         SA48         32K         148000 - 14FFFF           B         SA49         32K         150000 - 157FFF           B         SA50         32K         158000 - 15FFFF           B         SA51         32K         160000 - 167FFF           B         SA52         32K         168000 - 16FFFF           B         SA53         32K         170000 - 177FFF           B         SA53         32K         178000 - 17FFFF           B         SA54         32K         180000 - 187FFF           B         SA55         32K         180000 - 18FFFF           B         SA56         32K         190000 - 197FFF           B         SA57         32K         190000 - 19FFFF           B         SA58         32K         198000 - 19FFFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1BFFFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1C0000 - 1C7FFF           B         SA65         32K         1D8000 - 1DFFFF	
B SA49 32K 150000 - 157FFF B SA50 32K 158000 - 15FFFF B SA51 32K 160000 - 167FFF B SA52 32K 168000 - 16FFFF B SA53 32K 170000 - 177FFF B SA54 32K 178000 - 17FFFF B SA55 32K 180000 - 187FFF B SA56 32K 180000 - 187FFF B SA57 32K 190000 - 197FFF B SA58 32K 198000 - 19FFFF B SA59 32K 198000 - 19FFFF B SA60 32K 188000 - 18FFFF B SA60 32K 188000 - 18FFFF B SA61 32K 198000 - 187FFF B SA61 32K 180000 - 187FFF B SA61 32K 180000 - 187FFF B SA61 32K 180000 - 187FFF B SA62 32K 188000 - 187FFF B SA63 32K 180000 - 187FFF B SA63 32K 180000 - 187FFF B SA64 32K 180000 - 187FFF B SA65 32K 180000 - 187FFF B SA66 32K 180000 - 187FFF B SA68 32K 180000 - 187FFF C SA71 32K 200000 - 187FFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 207FFF C SA73 32K 210000 - 217FFF C SA74 32K 210000 - 217FFF	
B         SA50         32K         158000 - 15FFFF           B         SA51         32K         160000 - 167FFF           B         SA52         32K         168000 - 16FFFF           B         SA53         32K         170000 - 177FFF           B         SA54         32K         178000 - 17FFFF           B         SA55         32K         180000 - 187FFF           B         SA56         32K         190000 - 197FFF           B         SA57         32K         190000 - 197FFF           B         SA58         32K         198000 - 19FFFF           B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1D0000 - 1D7FFF           B         SA65         32K         1D0000 - 1D7FFF           B         SA66         32K         1D0000 - 1D7FFF           B         SA68         32K         1E8000 - 1E7FFF	
B SA51 32K 160000 - 167FFF B SA52 32K 168000 - 16FFFF B SA53 32K 170000 - 177FFF B SA54 32K 178000 - 17FFFF B SA55 32K 180000 - 18FFFF B SA56 32K 180000 - 18FFFF B SA57 32K 190000 - 19FFFF B SA58 32K 198000 - 19FFFF B SA59 32K 1A0000 - 1A7FFF B SA60 32K 1A8000 - 1AFFFF B SA61 32K 1B0000 - 1AFFFF B SA61 32K 1B0000 - 1AFFFF B SA62 32K 1B0000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C0000 - 1C7FFF B SA65 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF C SA71 32K 1E0000 - 1FFFFF C SA71 32K 200000 - 207FFF C SA72 32K 200000 - 207FFF C SA73 32K 210000 - 217FFF	
B SA52 32K 168000 - 16FFFF B SA53 32K 170000 - 177FFF B SA54 32K 178000 - 17FFFF B SA55 32K 180000 - 187FFF B SA56 32K 188000 - 18FFFF B SA57 32K 190000 - 197FFF B SA58 32K 198000 - 19FFFF B SA59 32K 1A0000 - 1A7FFF B SA60 32K 1A8000 - 1AFFFF B SA61 32K 1B0000 - 1AFFFF B SA62 32K 1B0000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF B SA66 32K 1D0000 - 1DFFFF C SA70 32K 1F8000 - 1FFFFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF	
B SA53 32K 170000 - 177FFF B SA54 32K 178000 - 17FFF B SA55 32K 180000 - 187FFF B SA56 32K 188000 - 18FFFF B SA57 32K 190000 - 197FFF B SA58 32K 198000 - 19FFFF B SA58 32K 198000 - 19FFFF B SA60 32K 1A0000 - 1A7FFF B SA61 32K 1B0000 - 1AFFFF B SA62 32K 1B0000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1DFFFF B SA66 32K 1D8000 - 1EFFFF B SA67 32K 1E8000 - 1EFFFF B SA68 32K 1F8000 - 1EFFFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF	
B         SA54         32K         178000 - 17FFFF           B         SA55         32K         180000 - 187FFF           B         SA56         32K         188000 - 18FFFF           B         SA57         32K         190000 - 197FFF           B         SA58         32K         198000 - 19FFFF           B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1B0000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1D0000 - 1D7FFF           B         SA65         32K         1D8000 - 1DFFFF           B         SA66         32K         1E0000 - 1E7FFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F8000 - 1F7FFF           B         SA69         32K         1F8000 - 1F7FFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF	
B         SA55         32K         180000 - 187FFF           B         SA56         32K         188000 - 18FFFF           B         SA57         32K         190000 - 197FFF           B         SA58         32K         198000 - 19FFFF           B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1B0000 - 1AFFFF           B         SA61         32K         1B8000 - 1BFFFF           B         SA62         32K         1B8000 - 1CFFFF           B         SA63         32K         1C8000 - 1CFFFF           B         SA64         32K         1D0000 - 1CFFFF           B         SA65         32K         1D8000 - 1DFFFF           B         SA66         32K         1E8000 - 1EFFFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F8000 - 1FFFFF           B         SA69         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA74         32K         218000 - 21FFFF	
B         SA56         32K         188000 - 18FFFF           B         SA57         32K         190000 - 197FFF           B         SA58         32K         198000 - 19FFFF           B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1C8000 - 1CFFFF           B         SA65         32K         1D8000 - 1D7FFF           B         SA66         32K         1D8000 - 1DFFFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA68         32K         1F8000 - 1FFFFF           B         SA69         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA74         32K         210000 - 217FFF	
B SA57 32K 190000 - 197FFF B SA58 32K 198000 - 19FFFF B SA59 32K 1A0000 - 1A7FFF B SA60 32K 1A8000 - 1AFFFF B SA61 32K 1B0000 - 1B7FFF B SA62 32K 1B8000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA63 32K 1C8000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1D7FFF B SA66 32K 1E8000 - 1E7FFF B SA68 32K 1E8000 - 1E7FFF B SA69 32K 1F8000 - 1F7FFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF	
B         SA58         32K         198000 - 19FFFF           B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1D0000 - 1D7FFF           B         SA65         32K         1D8000 - 1DFFFF           B         SA66         32K         1E0000 - 1E7FFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F8000 - 1F7FFF           B         SA70         32K         1F8000 - 1F7FFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
B         SA59         32K         1A0000 - 1A7FFF           B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1D0000 - 1CFFFF           B         SA65         32K         1D8000 - 1DFFFF           B         SA66         32K         1E0000 - 1E7FFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F8000 - 1FFFFF           B         SA70         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
B         SA60         32K         1A8000 - 1AFFFF           B         SA61         32K         1B0000 - 1B7FFF           B         SA62         32K         1B8000 - 1BFFFF           B         SA63         32K         1C0000 - 1C7FFF           B         SA64         32K         1D0000 - 1CFFFF           B         SA65         32K         1D8000 - 1D7FFF           B         SA66         32K         1E0000 - 1E7FFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F8000 - 1FFFFF           B         SA70         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
B SA61 32K 1B0000 - 1B7FFF B SA62 32K 1B8000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1DFFFF B SA66 32K 1E0000 - 1E7FFF B SA68 32K 1E8000 - 1EFFFF B SA69 32K 1F8000 - 1FFFFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF	
B SA62 32K 1B8000 - 1BFFFF B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1DFFFF B SA67 32K 1E0000 - 1E7FFF B SA68 32K 1E8000 - 1EFFFF B SA69 32K 1F0000 - 1F7FFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF	
B SA63 32K 1C0000 - 1C7FFF B SA64 32K 1C8000 - 1CFFFF B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1DFFFF B SA67 32K 1E0000 - 1E7FFF B SA68 32K 1E8000 - 1EFFFF B SA69 32K 1F0000 - 1F7FFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF C SA74 32K 218000 - 21FFFF	
B       SA64       32K       1C8000 - 1CFFFF         B       SA65       32K       1D0000 - 1D7FFF         B       SA66       32K       1D8000 - 1DFFFF         B       SA67       32K       1E0000 - 1E7FFF         B       SA68       32K       1E8000 - 1EFFFF         B       SA69       32K       1F0000 - 1F7FFF         B       SA70       32K       1F8000 - 1FFFFF         C       SA71       32K       200000 - 207FFF         C       SA72       32K       208000 - 20FFFF         C       SA73       32K       210000 - 217FFF         C       SA74       32K       218000 - 21FFFF	
B SA65 32K 1D0000 - 1D7FFF B SA66 32K 1D8000 - 1DFFFF B SA67 32K 1E0000 - 1E7FFF B SA68 32K 1E8000 - 1EFFFF B SA69 32K 1F0000 - 1F7FFF B SA70 32K 1F8000 - 1FFFFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF C SA74 32K 218000 - 21FFFF	
B         SA66         32K         1D8000 - 1DFFFF           B         SA67         32K         1E0000 - 1E7FFF           B         SA68         32K         1E8000 - 1EFFFF           B         SA69         32K         1F0000 - 1F7FFF           B         SA70         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
B SA67 32K 1E0000 - 1E7FFF B SA68 32K 1E8000 - 1EFFFF B SA69 32K 1F0000 - 1F7FFF B SA70 32K 1F8000 - 1FFFFF C SA71 32K 200000 - 207FFF C SA72 32K 208000 - 20FFFF C SA73 32K 210000 - 217FFF C SA74 32K 218000 - 21FFFF	
B       SA68       32K       1E8000 - 1EFFFF         B       SA69       32K       1F0000 - 1F7FFF         B       SA70       32K       1F8000 - 1FFFFF         C       SA71       32K       200000 - 207FFF         C       SA72       32K       208000 - 20FFFF         C       SA73       32K       210000 - 217FFF         C       SA74       32K       218000 - 21FFFF	
B       SA69       32K       1F0000 - 1F7FFF         B       SA70       32K       1F8000 - 1FFFFF         C       SA71       32K       200000 - 207FFF         C       SA72       32K       208000 - 20FFFF         C       SA73       32K       210000 - 217FFF         C       SA74       32K       218000 - 21FFFF	
B         SA70         32K         1F8000 - 1FFFFF           C         SA71         32K         200000 - 207FFF           C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
C       SA71       32K       200000 - 207FFF         C       SA72       32K       208000 - 20FFFF         C       SA73       32K       210000 - 217FFF         C       SA74       32K       218000 - 21FFFF	
C         SA72         32K         208000 - 20FFFF           C         SA73         32K         210000 - 217FFF           C         SA74         32K         218000 - 21FFFF	
C SA73 32K 210000 - 217FFF C SA74 32K 218000 - 21FFFF	
C SA74 32K 218000 - 21FFFF	
0 0475 001/ 000000 007555	
C SA75 32K 220000 - 227FFF	
C SA76 32K 228000 - 22FFFF	
C SA77 32K 230000 - 237FFF	
C SA78 32K 238000 - 23FFFF	
C SA79 32K 240000 - 247FFF	
C SA80 32K 248000 - 24FFFF	
C SA81 32K 250000 - 257FFF	
C SA82 32K 258000 - 25FFFF	
C SA83 32K 260000 - 267FFF	
C SA84 32K 268000 - 26FFFF	
C SA85 32K 270000 - 277FFF	
C SA86 32K 278000 - 27FFFF	
C SA87 32K 280000 - 287FFF	
C SA88 32K 288000 - 28FFFF	
C SA89 32K 290000 - 297FFF	





## **Memory Organization – AT49BV6416C (Continued)**

	y Organi		Brorres (continues)
Plane	Sector	Size (Words)	x16 Address Range (A21 - A0)
С	SA90	32K	298000 - 29FFFF
С	SA91	32K	2A0000 - 2A7FFF
С	SA92	32K	2A8000 - 2AFFFF
С	SA93	32K	2B0000 - 2B7FFF
С	SA94	32K	2B8000 - 2BFFFF
С	SA95	32K	2C0000 - 2C7FFF
С	SA96	32K	2C8000 - 2CFFFF
С	SA97	32K	2D0000 - 2D7FFF
С	SA98	32K	2D8000 - 2DFFFF
С	SA99	32K	2E0000 - 2E7FFF
С	SA100	32K	2E8000 - 2EFFFF
С	SA101	32K	2F0000 - 2F7FFF
С	SA102	32K	2F8000 - 2FFFFF
D	SA103	32K	300000 - 307FFF
D	SA104	32K	308000 - 30FFFF
D	SA105	32K	310000 - 317FFF
D	SA106	32K	318000 - 31FFFF
D	SA107	32K	320000 - 327FFF
D	SA108	32K	328000 - 32FFFF
D	SA109	32K	330000 - 337FFF
D	SA110	32K	338000 - 33FFFF
D	SA111	32K	340000 - 347FFF

## **Memory Organization – AT49BV6416C (Continued)**

	, organi		x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
D	SA112	32K	348000 - 34FFFF
D	SA113	32K	350000 - 357FFF
D	SA114	32K	358000 - 35FFFF
D	SA115	32K	360000 - 367FFF
D	SA116	32K	368000 - 36FFFF
D	SA117	32K	370000 - 377FFF
D	SA118	32K	378000 - 37FFFF
D	SA119	32K	380000 - 387FFF
D	SA120	32K	388000 - 38FFFF
D	SA121	32K	390000 - 397FFF
D	SA122	32K	398000 - 39FFFF
D	SA123	32K	3A0000 - 3A7FFF
D	SA124	32K	3A8000 - 3AFFFF
D	SA125	32K	3B0000 - 3B7FFF
D	SA126	32K	3B8000 - 3BFFFF
D	SA127	32K	3C0000 - 3C7FFF
D	SA128	32K	3C8000 - 3CFFFF
D	SA129	32K	3D0000 - 3D7FFF
D	SA130	32K	3D8000 - 3DFFFF
D	SA131	32K	3E0000 - 3E7FFF
D	SA132	32K	3E8000 - 3EFFFF
D	SA133	32K	3F0000 - 3F7FFF
D	SA134	32K	3F8000 - 3FFFFF

# **Memory Organization – AT49BV6416CT**

			x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
D	SA0	32K	00000 - 07FFF
D	SA1	32K	08000 - 0FFFF
D	SA2	32K	10000 - 17FFF
D	SA3	32K	18000 - 1FFFF
D	SA4	32K	20000 - 27FFF
D	SA5	32K	28000 - 2FFFF
D	SA6	32K	30000 - 37FFF
D	SA7	32K	38000 - 3FFFF
D	SA8	32K	40000 - 47FFF
D	SA9	32K	48000 - 4FFFF
D	SA10	32K	50000 - 57FFF
D	SA11	32K	58000 - 5FFFF
D	SA12	32K	60000 - 67FFF
D	SA13	32K	68000 - 6FFFF
D	SA14	32K	70000 - 77FFF
D	SA15	32K	78000 - 7FFFF
D	SA16	32K	80000 - 87FFF
D	SA17	32K	88000 - 8FFFF
D	SA18	32K	90000 - 97FFF
D	SA19	32K	98000 - 9FFFF
D	SA20	32K	A0000 - A7FFF
D	SA21	32K	A8000 - AFFFF
D	SA22	32K	B0000 - B7FFF
D	SA23	32K	B8000 - BFFFF
D	SA24	32K	C0000 - C7FFF
D	SA25	32K	C8000 - CFFFF
D	SA26	32K	D0000 - D7FFF
D	SA27	32K	D8000 - DFFFF
D	SA28	32K	E0000 - E7FFF
D	SA29	32K	E8000 - EFFFF
D	SA30	32K	F0000 - F7FFF
D	SA31	32K	F8000 - FFFFF
С	SA32	32K	100000 - 107FFF
С	SA33	32K	108000 - 10FFFF
С	SA34	32K	110000 - 117FFF
С	SA35	32K	118000 - 11FFFF
С	SA36	32K	120000 - 127FFF
С	SA37	32K	128000 - 12FFFF
С	SA38	32K	130000 - 137FFF
С	SA39	32K	138000 - 13FFFF
С	SA40	32K	140000 - 147FFF
С	SA41	32K	148000 - 14FFFF
С	SA42	32K	150000 - 157FFF
С	SA43	32K	158000 - 15FFFF
<u> </u>	1	I.	<u>I</u>

## **Memory Organization – AT49BV6416CT (Continued)**

			x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
С	SA44	32K	160000 - 167FFF
С	SA45	32K	168000 - 16FFFF
С	SA46	32K	170000 - 177FFF
С	SA47	32K	178000 - 17FFFF
С	SA48	32K	180000 - 187FFF
С	SA49	32K	188000 - 18FFFF
С	SA50	32K	190000 - 197FFF
С	SA51	32K	198000 - 19FFFF
С	SA52	32K	1A0000 - 1A7FFF
С	SA53	32K	1A8000 - 1AFFFF
С	SA54	32K	1B0000 - 1B7FFF
С	SA55	32K	1B8000 - 1BFFFF
С	SA56	32K	1C0000 - 1C7FFF
С	SA57	32K	1C8000 - 1CFFFF
С	SA58	32K	1D0000 - 1D7FFF
С	SA59	32K	1D8000 - 1DFFFF
С	SA60	32K	1E0000 - 1E7FFF
С	SA61	32K	1E8000 - 1EFFFF
С	SA62	32K	1F0000 - 1F7FFF
С	SA63	32K	1F8000 - 1FFFFF
В	SA64	32K	200000 - 207FFF
В	SA65	32K	208000 - 20FFFF
В	SA66	32K	210000 - 217FFF
В	SA67	32K	218000 - 21FFFF
В	SA68	32K	220000 - 227FFF
В	SA69	32K	228000 - 22FFFF
В	SA70	32K	230000 - 237FFF
В	SA71	32K	238000 - 23FFFF
В	SA72	32K	240000 - 247FFF
В	SA73	32K	248000 - 24FFFF
В	SA74	32K	250000 - 257FFF
В	SA75	32K	258000 - 25FFFF
В	SA76	32K	260000 - 267FFF
В	SA77	32K	268000 - 26FFFF
В	SA78	32K	270000 - 277FFF
В	SA79	32K	278000 - 27FFFF
В	SA80	32K	280000 - 287FFF
В	SA81	32K	288000 - 28FFFF
В	SA82	32K	290000 - 297FFF
В	SA83	32K	298000 -29FFFF
В	SA84	32K	2A0000 - 2A7FFF
В	SA85	32K	2A8000 - 2AFFFF
В	SA86	32K	2B0000 - 2B7FFF
В	SA87	32K	2B8000 - 2BFFFF





## **Memory Organization – AT49BV6416CT (Continued)**

_			x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
В	SA88	32K	2C0000 - 2C7FFF
В	SA89	32K	2C8000 - 2CFFFF
В	SA90	32K	2D0000 - 2D7FFF
В	SA91	32K	2D8000 - 2DFFFF
В	SA92	32K	2E0000 - 2E7FFF
В	SA93	32K	2E8000 - 2EFFFF
В	SA94	32K	2F0000 - 2F7FFF
В	SA95	32K	2F8000 - 2FFFFF
Α	SA96	32K	300000 - 307FFF
Α	SA97	32K	308000 - 30FFFF
Α	SA98	32K	310000 - 317FFF
Α	SA99	32K	318000 - 31FFFF
Α	SA100	32K	320000 - 327FFF
Α	SA101	32K	328000 - 32FFFF
Α	SA102	32K	330000 - 337FFF
Α	SA103	32K	338000 - 33FFFF
Α	SA104	32K	340000 - 347FFF
Α	SA105	32K	348000 - 34FFFF
Α	SA106	32K	350000 - 357FFF
Α	SA107	32K	358000 - 35FFFF
Α	SA108	32K	360000 - 367FFF
Α	SA109	32K	368000 - 36FFFF
Α	SA110	32K	370000 - 377FFF
Α	SA111	32K	378000 - 37FFFF

## **Memory Organization – AT49BV6416CT (Continued)**

			x16
Plane	Sector	Size (Words)	Address Range (A21 - A0)
Α	SA112	32K	380000 - 387FFF
Α	SA113	32K	388000 - 38FFFF
Α	SA114	32K	390000 - 397FFF
Α	SA115	32K	398000 - 39FFFF
Α	SA116	32K	3A0000 - 3A7FFF
Α	SA117	32K	3A8000 - 3AFFFF
Α	SA118	32K	3B0000 - 3B7FFF
Α	SA119	32K	3B8000 - 3BFFFF
Α	SA120	32K	3C0000 - 3C7FFF
Α	SA121	32K	3C8000 - 3CFFFF
Α	SA122	32K	3D0000 - 3D7FFF
Α	SA123	32K	3D8000 - 3DFFFF
Α	SA124	32K	3E0000 - 3E7FFF
Α	SA125	32K	3E8000 - 3EFFFF
Α	SA126	32K	3F0000 - 3F7FFF
Α	SA127	4K	3F8000 - 3F8FFF
Α	SA128	4K	3F9000 - 3F9FFF
Α	SA129	4K	3FA000 - 3FAFFF
Α	SA130	4K	3FB000 - 3FBFFF
Α	SA131	4K	3FC000 - 3FCFFF
Α	SA132	4K	3FD000 - 3FDFFF
Α	SA133	4K	3FE000 - 3FEFFF
Α	SA134	4K	3FF000 - 3FFFFF

# **DC and AC Operating Range**

	AT49BV6416C(T)-70
Operating Temperature (Case)	-40°C - 85°C
V <sub>CC</sub> Power Supply	2.7V - 3.6V

# **Operating Modes**

Mode	CE	ŌĒ	WE	RESET	<b>V</b> <sub>PP</sub> <sup>(4)</sup>	Ai	I/O
Read	$V_{IL}$	V <sub>IL</sub>	$V_{IH}$	V <sub>IH</sub>	Х	Ai	D <sub>OUT</sub>
Program/Erase <sup>(3)</sup>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IHPP</sub> <sup>(5)</sup>	Ai	D <sub>IN</sub>
Standby/Program Inhibit	V <sub>IH</sub>	X <sup>(1)</sup>	х	V <sub>IH</sub>	Х	×	High Z
	Х	Х	$V_{IH}$	V <sub>IH</sub>	Х		
Program Inhibit	Х	V <sub>IL</sub>	Х	V <sub>IH</sub>	Х		
	Х	Х	Х	Х	V <sub>ILPP</sub> <sup>(6)</sup>		
Output Disable	Х	V <sub>IH</sub>	Х	V <sub>IH</sub>	Х		High Z
Reset	Х	Х	Х	V <sub>IL</sub>	Х	X	High Z
Product Identification							
Cathurava				V		A0 = V <sub>IL</sub> , A1 - A21 = V <sub>IL</sub>	Manufacturer Code <sup>(3)</sup>
Software				V <sub>IH</sub>		A0 = V <sub>IH</sub> , A1 - A21 = V <sub>IL</sub>	Device Code <sup>(3)</sup>

Notes:

- X can be VIL or VIH.
- 2. Refer to AC programming waveforms.
- 3. Manufacturer Code: 001FH; Device Code: 00C5H AT49BV6416C; 00DFH AT49BV6416CT
- 4. The VPP pin can be tied to  $V_{CC}$ . For faster program/erase operations,  $V_{PP}$  can be set to 12.0V  $\pm$  0.5V. 5.  $V_{IHPP}$  (min) = 1.65V.
- 6.  $V_{ILPP}(max) = 0.7V$ .

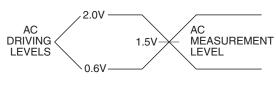


# **DC Characteristics**

Symbol	Parameter	Condition	Min	Max	Units
ILI	Input Load Current	$V_{IN} = 0V \text{ to } V_{CC}$		1	μΑ
I <sub>LO</sub>	Output Leakage Current	$V_{I/O} = OV \text{ to } V_{CC}$		1	μΑ
I <sub>SB1</sub>	V <sub>CC</sub> Standby Current CMOS	$\overline{\text{CE}} = \text{V}_{\text{CCQ}} - 0.3 \text{V to V}_{\text{CC}}$		35	μΑ
I <sub>CC</sub> <sup>(1)</sup>	V <sub>CC</sub> Active Current	f = 5 MHz; I <sub>OUT</sub> = 0 mA		30	mA
I <sub>CCRE</sub>	V <sub>CC</sub> Read While Erase Current	$f = 5 \text{ MHz}; I_{OUT} = 0 \text{ mA}$		60	mA
I <sub>CCRW</sub>	V <sub>CC</sub> Read While Write Current	f = 5 MHz; I <sub>OUT</sub> = 0 mA		60	mA
V <sub>IL</sub>	Input Low Voltage			0.6	V
V <sub>IH</sub>	Input High Voltage		V <sub>CCQ</sub> - 0.6		V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 2.1 mA		0.45	V
V <sub>OH</sub>	Output High Voltage	$I_{OH} = -100 \mu A; V_{CCQ} = 2.2V - 3.6V$	V <sub>CCQ</sub> - 0.1		V

Note: 1. In the erase mode,  $I_{CC}$  is 35 mA.

# **Input Test Waveforms and Measurement Level**



 $t_R$ ,  $t_F < 5 \text{ ns}$ 

# **Output Test Load**

# Pin Capacitance

 $f = 1 \text{ MHz}, T = 25^{\circ}C^{(1)}$ 

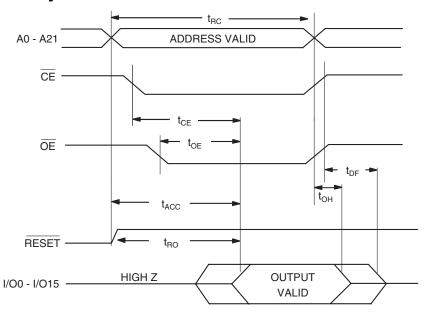
	Тур	Max	Units	Conditions
C <sub>IN</sub>	4	6	pF	$V_{IN} = 0V$
C <sub>OUT</sub>	8	12	pF	V <sub>OUT</sub> = 0V

Note: 1. This parameter is characterized and is not 100% tested.

# **AC Asynchronous Read Timing Characteristics**

Symbol	Parameter	Min	Max	Units
t <sub>RC</sub>	Read Cycle Time	70		ns
t <sub>ACC</sub>	Access, Address to Data Valid		70	ns
t <sub>CE</sub>	Access, CE to Data Valid		70	ns
t <sub>OE</sub>	OE to Data Valid		20	ns
t <sub>DF</sub>	CE, OE High to Data Float		25	ns
t <sub>OH</sub>	Output Hold from $\overline{OE}$ , $\overline{CE}$ or Address, whichever Occurs First	0		ns
t <sub>RO</sub>	RESET to Output Delay		150	ns

# **Asynchronous Read Cycle Waveform**(1)(2)(3)



- Notes: 1.  $\overline{CE}$  may be delayed up to  $t_{ACC}$   $t_{CE}$  after the address transition without impact on  $t_{ACC}$ .

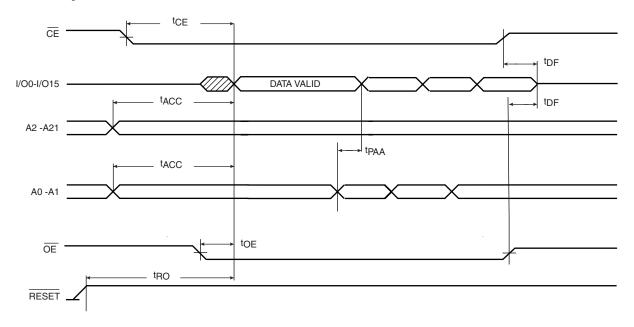
  2.  $\overline{OE}$  may be delayed up to  $t_{CE}$   $t_{OE}$  after the falling edge of  $\overline{CE}$  without impact on  $t_{CE}$  or by  $t_{ACC}$   $t_{OE}$  after an address change without impact on  $t_{ACC}$ . 3.  $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first (CL = 5 pF).



# **AC Asynchronous Read Timing Characteristics**

Symbol	Parameter	Min	Max	Units
t <sub>ACC</sub>	Access, Address to Data Valid		70	ns
t <sub>CE</sub>	Access, CE to Data Valid		70	ns
t <sub>OE</sub>	OE to Data Valid		20	ns
t <sub>DF</sub>	CE, OE High to Data Float		25	ns
t <sub>RO</sub>	RESET to Output Delay		150	ns
t <sub>PAA</sub>	Page Address Access Time		20	ns

# **Page Read Cycle Waveform**

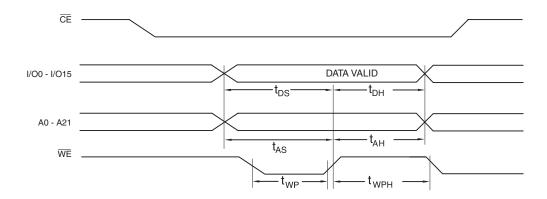


## **AC Word Load Characteristics**

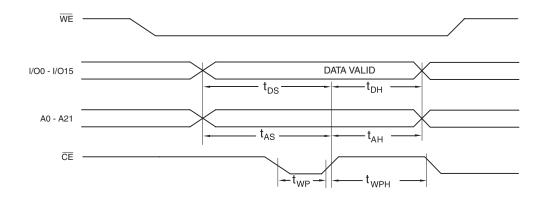
Symbol	Parameter	Min	Max	Units
t <sub>AS</sub>	Address Setup Time to WE and CE High	50		ns
t <sub>AH</sub>	Address Hold Time	0		ns
t <sub>DS</sub>	Data Setup Time	50		ns
t <sub>DH</sub>	Data Hold Time	0		ns
t <sub>WP</sub>	CE or WE Low Pulse Width	35		ns
t <sub>WPH</sub>	CE or WE High Pulse Width	25		ns

## **AC Word Load Waveforms**

# **WE** Controlled



## **CE** Controlled

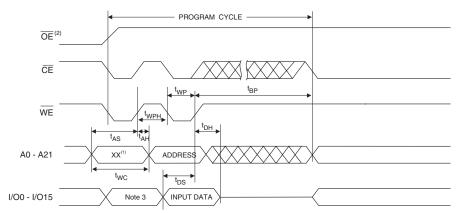




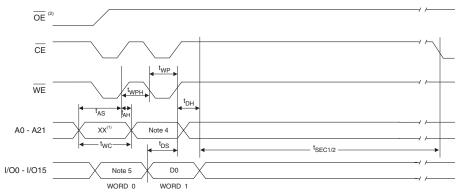
# **Program Cycle Characteristics**

Symbol	Parameter	Min	Тур	Max	Units
t <sub>BP</sub>	Word Programming Time		15		μs
t <sub>SEC1</sub>	Sector Erase Cycle Time (4K word sectors)		200		ms
t <sub>SEC2</sub>	Sector Erase Cycle Time (32K word sectors)		700		ms
t <sub>ES</sub>	Erase Suspend Time			15	μs
t <sub>PS</sub>	Program Suspend Time			10	μs
t <sub>ERES</sub>	Delay between Erase Resume and Erase Suspend	500			μs

# **Program Cycle Waveforms**



# Sector, Plane or Chip Erase Cycle Waveforms



- Notes: 1. Any address can be used to load data.
  - 2.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.
  - 3. The data can be 40H or 10H.
  - 4. For chip erase, any address can be used. For plane erase or sector erase, the address depends on what plane or sector is
  - 5. For chip erase, the data should be 21H, for plane erase, the data should be 22H, and for sector erase, the data should be 20H.

Table 5. Common Flash Interface Definition for AT49BV6416C(T)

Address	AT49BV6416CT	AT49BV6416C	Comments
10h	0051h	0051h	"Q"
11h	0052h	0052h	"R"
12h	0059h	0059h	"Y"
13h	0003h	0003h	
14h	0000h	0000h	
15h	0041h	0041h	
16h	0000h	0000h	
17h	0000h	0000h	
18h	0000h	0000h	
19h	0000h	0000h	
1Ah	0000h	0000h	
1Bh	0027h	0027h	VCC min write/erase
1Ch	0036h	0036h	VCC max write/erase
1Dh	00B5h	00B5h	VPP min voltage
1Eh	00C5h	00C5h	VPP max voltage
1Fh	0004h	0004h	Typ word write – 15 μs
20h	0000h	0000h	
21h	0009h	0009h	Typ block erase – 500 ms
22h	0010h	0010h	Typ chip erase – 64,300 ms
23h	0004h	0004h	Max word write/typ time
24h	0000h	0000h	n/a
25h	0003h	0003h	Max block erase/typ block erase
26h	0003h	0003h	Max chip erase/ typ chip erase
27h	0017h	0017h	Device size
28h	0001h	0001h	x16 device
29h	0000h	0000h	x16 device
2Ah	0000h	0000h	Multiple byte write not supported
2Bh	0000h	0000h	Multiple byte write not supported
2Ch	0002h	0002h	2 regions, x = 2
2Dh	007Eh	0007h	64K bytes, Y = 126 (Top); 8K bytes, Y = 7 (Bottom)
2Eh	0000h	0000h	64K bytes, Y = 126 (Top); 8K bytes, Y = 7 (Bottom)
2Fh	0000h	0020h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)
30h	0001h	0000h	64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom)
31h	0007h	007Eh	8K bytes, Y = 7 (Top); 64K bytes, Y = 126 (Bottom)
32h	0000h	0000h	8K bytes, Y = 7 (Top); 64K bytes, Y = 126 (Bottom)
33h	0020h	0000h	8K bytes, Z = 32 (Top);64K bytes, Z = 256 (Bottom)
34h	0000h	0001h	8K bytes, Z = 32 (Top);64K bytes, Z = 256 (Bottom)





**Table 5.** Common Flash Interface Definition for AT49BV6416C(T) (Continued)

Address	AT49BV6416CT	AT49BV6416C	Comments
		VENDOR SPECIFIC	EXTENDED QUERY
41h	0050h	0050h	"P"
42h	0052h	0052h	"R"
43h	0049h	0049h	"l"
44h	0031h	0031h	Major version number, ASCII
45h	0030h	0030h	Minor version number, ASCII
46h	00AFh	00AFh	Bit 0 – chip erase supported, 0 – no, 1 – yes  Bit 1 – erase suspend supported, 0 – no, 1 – yes  Bit 2 – program suspend supported, 0 – no, 1 – yes  Bit 3 – simultaneous operations supported, 0 – no, 1 – yes  Bit 4 – burst mode read supported, 0 – no, 1 – yes  Bit 5 – page mode read supported, 0 – no, 1 – yes  Bit 6 – queued erase supported, 0 – no, 1 – yes  Bit 7 – protection bits supported, 0 – no, 1 – yes
47h	0000h	0001h	Bit 0 – top ("0") or bottom ("1") boot block device Undefined bits are "0"
48h	0000h	0000h	Bit 0 – 4 word linear burst with wrap around, 0 – no, 1 – yes Bit 1 – 8 word linear burst with wrap around, 0 – no, 1 – yes Bit 2 – 16 word linear burst with wrap around, 0 – no, 1 – yes Bit 3 – continuous burst, 0 – no, 1 – yes Undefined bits are "0"
49h	0001h	0001h	Bit 0 – 4 word page, 0 – no, 1 – yes Bit 1 – 8 word page, 0 – no, 1 – yes Undefined bits are "0"
4Ah	0080h	0080h	Location of protection register lock byte, the section's first byte
4Bh	0003h	0003h	# of bytes in the factory prog section of prot register – 2*n
4Ch	0003h	0003h	# of bytes in the user prog section of prot register – 2*n

# AT49BV6416C(T) Ordering Information

t <sub>ACC</sub> (ns)	I <sub>CC</sub> (mA)				
	Active	Standby	Ordering Code	Package	Operation Range
70	30	0.035	AT49BV6416C-70CI	48C20	Industrial (-40° to 85°C)
70	30	0.035	AT49BV6416CT-70CI	48C20	Industrial (-40° to 85°C)

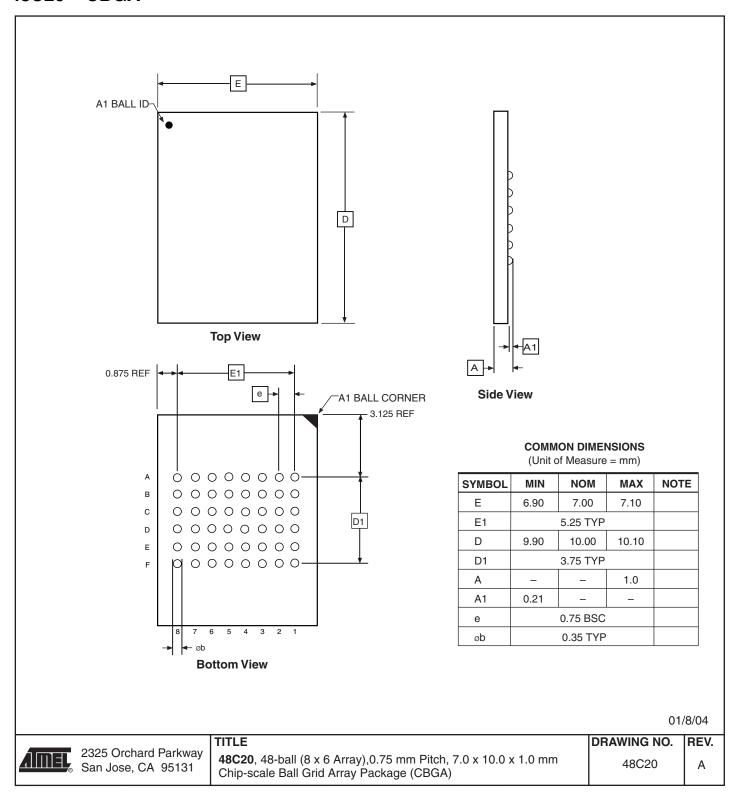
Package Type				
48C20	48-ball, Plastic Chip-size Ball Grid Array Package (CBGA)			





# Packaging Information - AT49BV6416C(T)

## 48C20 - CBGA



# Revision History

Revision No.	History		
Revision A – April 2004	Initial Release		
Revision B – November 2004	<ul> <li>Removed "Preliminary" from the datasheet.</li> <li>Modified note 6 and added notes 7 and 10 on page 13.</li> <li>Removed note 1 and added note 2 on page 14.</li> <li>Changed the I<sub>SB1</sub> spec to 35 µA.</li> </ul>		





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